



BGS67A

65 MHz, 25.5 dB gain reverse amplifier

Rev. 05 — 11 March 2005

Product data sheet

1. Product profile

1.1 General description

Hybrid high dynamic range amplifier module in a leadless SOT567A package, operating at a supply voltage of 12 V.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- Extremely low noise
- Excellent linearity
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability

1.3 Applications

- Reverse amplifier in two-way CATV systems in the 5 MHz to 65 MHz frequency range

1.4 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
G_p	power gain	$f = 10$ MHz	25	-	26	dB	
I_{tot}	total current consumption (DC)	$V_B = 12$ V	[1]	75	-	95	mA

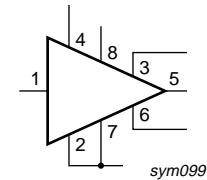
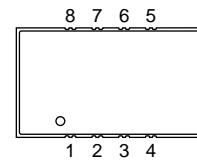
[1] The module normally operates at $V_B = 12$ V, but is able to withstand supply transients up to 30 V.

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2. Pinning information

Table 2: Pinning

Pin	Description	Simplified outline	Symbol
1	input		
2	common		
3	provision		
4	+V _B		
5	output		
6	provision		
7	common		
8	+V _B		



3. Ordering information

Table 3: Ordering information

Type number	Package			Version
	Name	Description		
BGS67A	-	leadless surface mounted package; plastic cap; 8 terminations		SOT567A

4. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _i	RF input voltage		-	55	dBmV
T _{sig}	storage temperature		-40	+100	°C
T _{mb}	mounting base temperature		-20	+100	°C



5. Characteristics

Table 5: Characteristics

Bandwidth 5 MHz to 65 MHz; $V_B = 12$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
G_p	power gain	$f = 10$ MHz	25	-	26	dB	
SL	slope cable equivalent	$f = 5$ MHz to 65 MHz	-0.1	-	+0.6	dB	
FL	flatness of frequency response	$f = 5$ MHz to 65 MHz	-	-	±0.2	dB	
s_{11}	input return losses	$f = 5$ MHz to 65 MHz	20	-	-	dB	
s_{22}	output return losses	$f = 5$ MHz to 65 MHz	20	-	-	dB	
CTB	composite triple beat	4 channels flat; $V_o = 50$ dBmV; measured at 25 MHz	-	-	-64	dB	
X_{mod}	cross modulation	4 channels flat; $V_o = 50$ dBmV; measured at 25 MHz	-	-	-54	dB	
d_2	second order distortion		[1]	-	-70	dB	
NF	noise figure	$f = 65$ MHz	-	-	3.5	dB	
I_{tot}	total current consumption		[2]	75	-	95	mA

[1] $f_p = 19$ MHz; $V_p = 50$ dBmV; $f_q = 31$ MHz; $V_q = 50$ dBmV; measured at $f_p + f_q = 50$ MHz.

[2] The module normally operates at $V_B = 12$ V, but is able to withstand supply transients up to 30 V.

6. Package outline

Leadless surface mounted package; plastic cap; 8 terminations

SOT567A

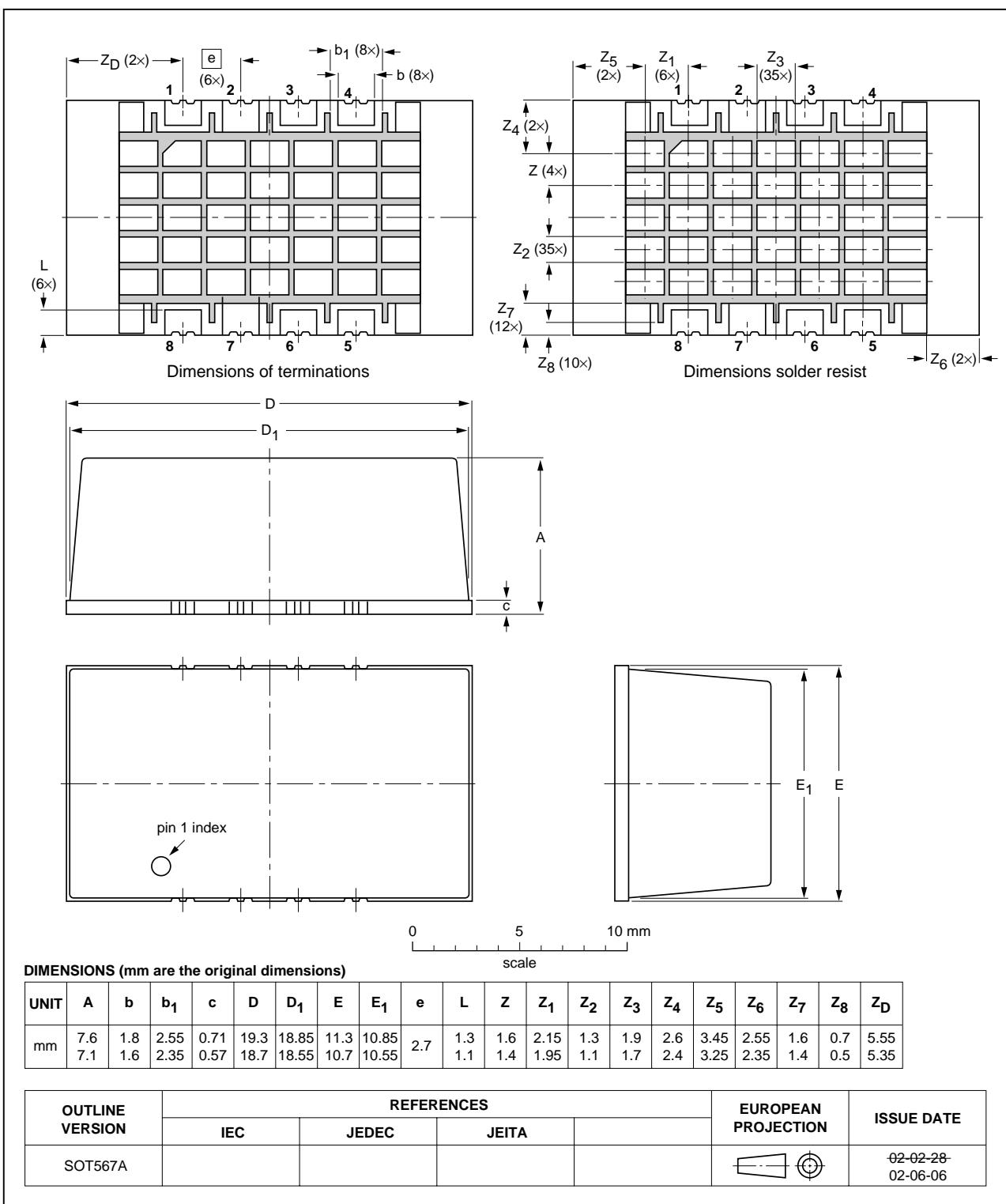


Fig 1. Package outline SOT567A



7. Revision history

Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BGS67A_5	20050311	Product data sheet	-	9397 750 14736	BGS67A_4
Modifications:	<ul style="list-style-type: none"> The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors. 				
BGS67A_4	20020906	Product specification	-	9397 750 10107	BGS67A_N_3
BGS67A_N_3	20020606	Preliminary specification	-	9397 750 10083	BGS67A_N_2
BGS67A_N_2	20011016	Preliminary specification	-	9397 750 08961	BGS67A_N_1
BGS67A_N_1	20010417	Preliminary specification	-	9397 750 08265	-

8. Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2][3]}	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

9. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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12. Contents

1	Product profile	1
1.1	General description	1
1.2	Features	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Characteristics	3
6	Package outline	4
7	Revision history	5
8	Data sheet status	6
9	Definitions	6
10	Disclaimers	6
11	Contact information	6

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